

# MJE15028, MJE15030 (NPN), MJE15029, MJE15031 (PNP)

## Complementary Silicon Plastic Power Transistors

These devices are designed for use as high-frequency drivers in audio amplifiers.

### Features

- High Current Gain – Bandwidth Product
- TO-220 Compact Package
- These Devices are Pb-Free and are RoHS Compliant\*

### MAXIMUM RATINGS

| Rating                                                                                    | Symbol         | Value        | Unit                     |
|-------------------------------------------------------------------------------------------|----------------|--------------|--------------------------|
| Collector-Emitter Voltage<br>MJE15028G, MJE15029G<br>MJE15030G, MJE15031G                 | $V_{CEO}$      | 120<br>150   | Vdc                      |
| Collector-Base Voltage<br>MJE15028G, MJE15029G<br>MJE15030G, MJE15031G                    | $V_{CB}$       | 120<br>150   | Vdc                      |
| Emitter-Base Voltage                                                                      | $V_{EB}$       | 5.0          | Vdc                      |
| Collector Current – Continuous                                                            | $I_C$          | 8.0          | Adc                      |
| Collector Current – Peak                                                                  | $I_{CM}$       | 16           | Adc                      |
| Base Current                                                                              | $I_B$          | 2.0          | Adc                      |
| Total Device Dissipation<br>@ $T_C = 25^\circ\text{C}$<br>Derate above $25^\circ\text{C}$ | $P_D$          | 50<br>0.40   | W<br>W/ $^\circ\text{C}$ |
| Total Device Dissipation<br>@ $T_A = 25^\circ\text{C}$<br>Derate above $25^\circ\text{C}$ | $P_D$          | 2.0<br>0.016 | W<br>W/ $^\circ\text{C}$ |
| Operating and Storage Junction<br>Temperature Range                                       | $T_J, T_{stg}$ | -65 to +150  | $^\circ\text{C}$         |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

### THERMAL CHARACTERISTICS

| Characteristics                         | Symbol          | Max  | Unit               |
|-----------------------------------------|-----------------|------|--------------------|
| Thermal Resistance, Junction-to-Case    | $R_{\theta JC}$ | 2.5  | $^\circ\text{C/W}$ |
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 62.5 | $^\circ\text{C/W}$ |

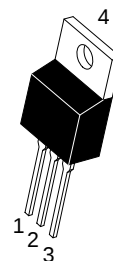
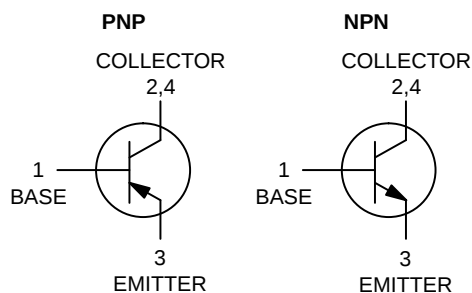
\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



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## 8 AMPERE POWER TRANSISTORS COMPLEMENTARY SILICON 120-150 VOLTS, 50 WATTS



TO-220  
CASE 221A  
STYLE 1

### MARKING DIAGRAM



MJE150xx = Device Code  
x = 28, 29, 30, or 31  
A = Assembly Location  
Y = Year  
WW = Work Week  
G = Pb-Free Package

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

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## ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ\text{C}$ unless otherwise noted)

| Characteristic                                                                                                                                                 | Symbol        | Min        | Max        | Unit            |
|----------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------|------------|------------|-----------------|
| <b>OFF CHARACTERISTICS</b>                                                                                                                                     |               |            |            |                 |
| Collector-Emitter Sustaining Voltage (Note 1)<br>( $I_C = 10\text{ mAdc}$ , $I_B = 0$ )<br>MJE15028, MJE15029<br>MJE15030, MJE15031                            | $V_{CE(sus)}$ | 120<br>150 | –<br>–     | Vdc             |
| Collector Cutoff Current<br>( $V_{CE} = 120\text{ Vdc}$ , $I_B = 0$ )<br>MJE15028, MJE15029<br>( $V_{CE} = 150\text{ Vdc}$ , $I_B = 0$ )<br>MJE15030, MJE15031 | $I_{CEO}$     | –<br>–     | 0.1<br>0.1 | mAdc            |
| Collector Cutoff Current<br>( $V_{CB} = 120\text{ Vdc}$ , $I_E = 0$ )<br>MJE15028, MJE15029<br>( $V_{CB} = 150\text{ Vdc}$ , $I_E = 0$ )<br>MJE15030, MJE15031 | $I_{CBO}$     | –<br>–     | 10<br>10   | $\mu\text{Adc}$ |
| Emitter Cutoff Current<br>( $V_{BE} = 5.0\text{ Vdc}$ , $I_C = 0$ )                                                                                            | $I_{EBO}$     | –          | 10         | $\mu\text{Adc}$ |

## ON CHARACTERISTICS (Note 1)

|                                                                                                                                                                                                                                                         |               |                      |                  |     |
|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------|----------------------|------------------|-----|
| DC Current Gain<br>( $I_C = 0.1\text{ Adc}$ , $V_{CE} = 2.0\text{ Vdc}$ )<br>( $I_C = 2.0\text{ Adc}$ , $V_{CE} = 2.0\text{ Vdc}$ )<br>( $I_C = 3.0\text{ Adc}$ , $V_{CE} = 2.0\text{ Vdc}$ )<br>( $I_C = 4.0\text{ Adc}$ , $V_{CE} = 2.0\text{ Vdc}$ ) | $h_{FE}$      | 40<br>40<br>40<br>20 | –<br>–<br>–<br>– | –   |
| DC Current Gain Linearity<br>( $V_{CE}$ From 2.0 V to 20 V, $I_C$ From 0.1 A to 3 A)<br>(NPN to PNP)                                                                                                                                                    | $h_{FE}$      | Typ<br>2<br>3        |                  |     |
| Collector-Emitter Saturation Voltage<br>( $I_C = 1.0\text{ Adc}$ , $I_B = 0.1\text{ Adc}$ )                                                                                                                                                             | $V_{CE(sat)}$ | –                    | 0.5              | Vdc |
| Base-Emitter On Voltage<br>( $I_C = 1.0\text{ Adc}$ , $V_{CE} = 2.0\text{ Vdc}$ )                                                                                                                                                                       | $V_{BE(on)}$  | –                    | 1.0              | Vdc |

## DYNAMIC CHARACTERISTICS

|                                                                                                                                  |       |    |   |     |
|----------------------------------------------------------------------------------------------------------------------------------|-------|----|---|-----|
| Current Gain – Bandwidth Product (Note 2)<br>( $I_C = 500\text{ mAdc}$ , $V_{CE} = 10\text{ Vdc}$ , $f_{test} = 10\text{ MHz}$ ) | $f_T$ | 30 | – | MHz |
|----------------------------------------------------------------------------------------------------------------------------------|-------|----|---|-----|

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width  $\leq 300\text{ }\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .
2.  $f_T = |h_{fe}| \cdot f_{test}$ .

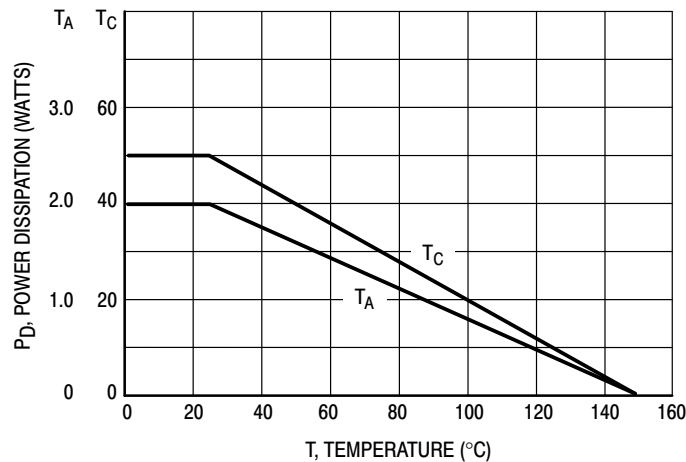


Figure 1. Power Derating

# MJE15028, MJE15030 (NPN), MJE15029, MJE15031 (PNP)

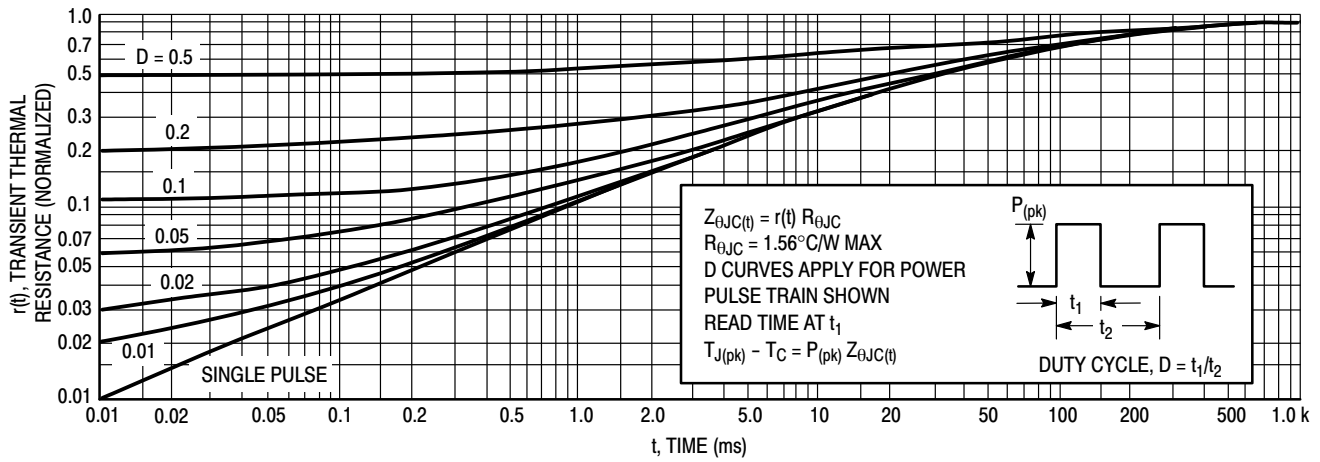


Figure 2. Thermal Response

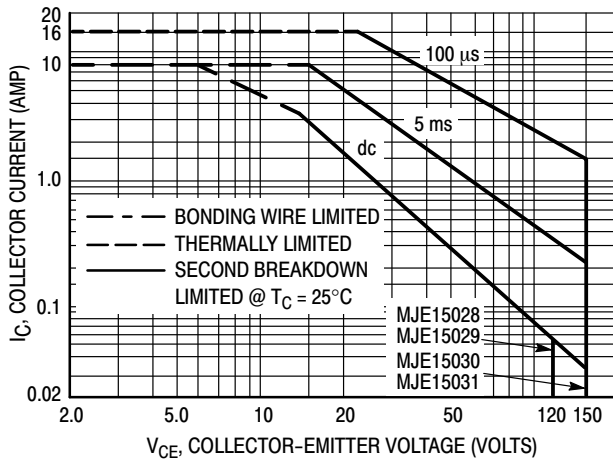


Figure 3. Forward Bias Safe Operating Area

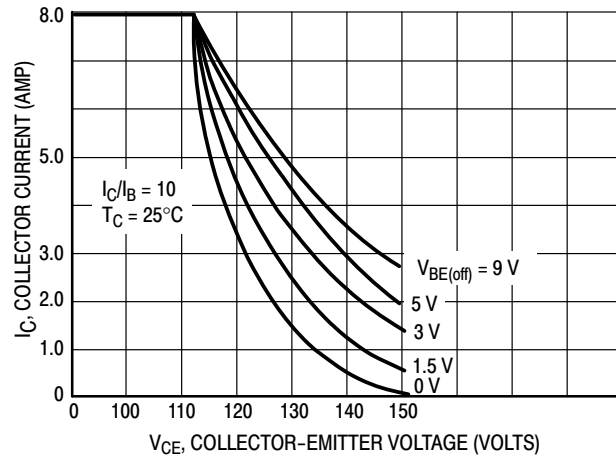


Figure 4. Reverse-Bias Switching Safe Operating Area

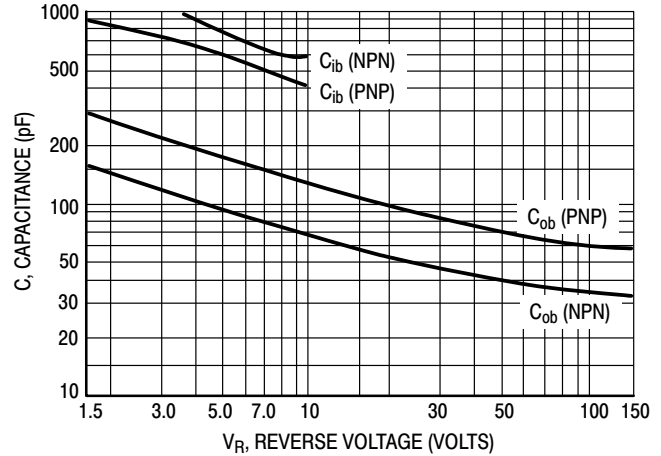


Figure 5. Capacitances

# MJE15028, MJE15030 (NPN), MJE15029, MJE15031 (PNP)

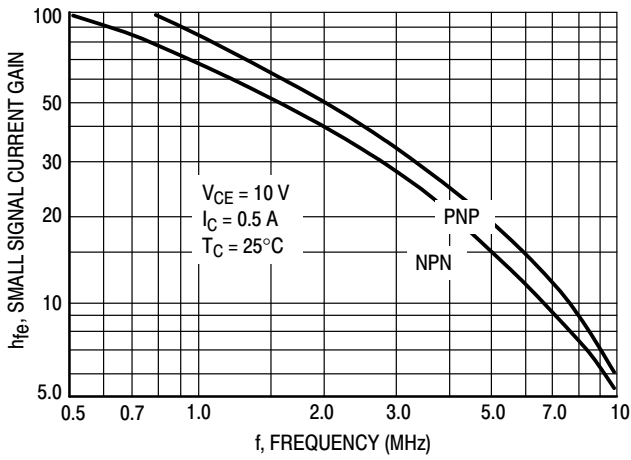


Figure 6. Small-Signal Current Gain

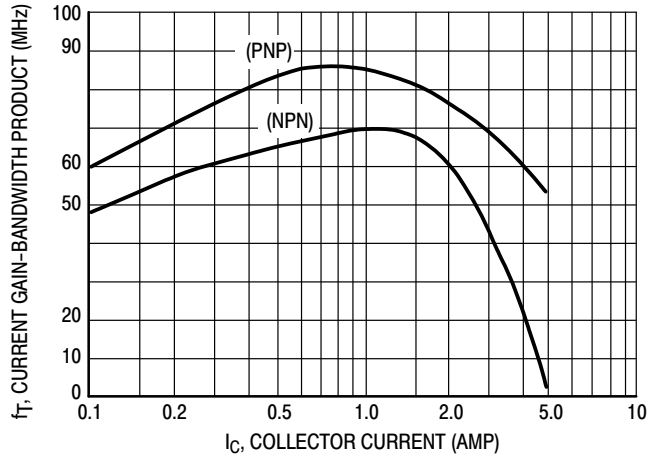
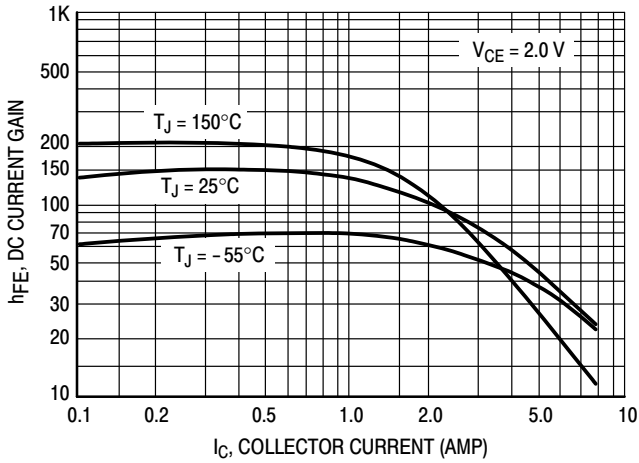


Figure 7. Current Gain-Bandwidth Product

## NPN — MJE15028 MJE15030



## PNP — MJE15029 MJE15031

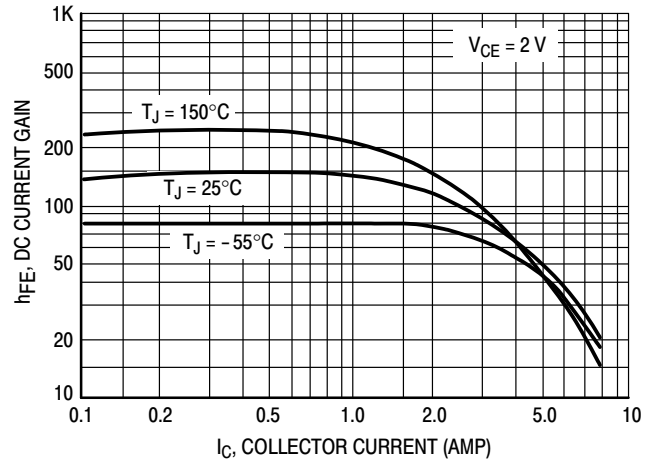
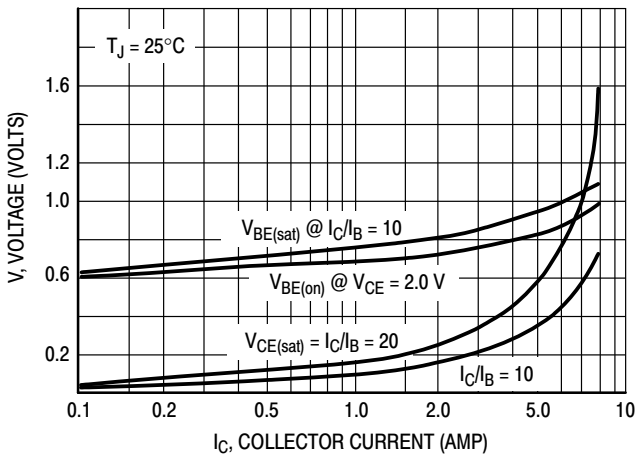


Figure 8. DC Current Gain

## NPN



## PNP

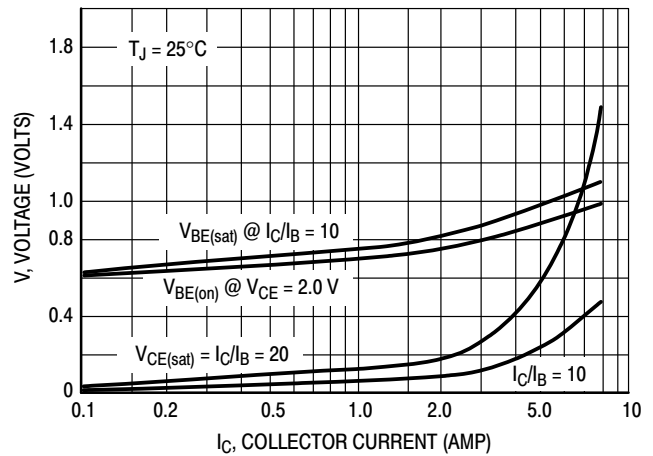


Figure 9. "On" Voltage

## MJE15028, MJE15030 (NPN), MJE15029, MJE15031 (PNP)

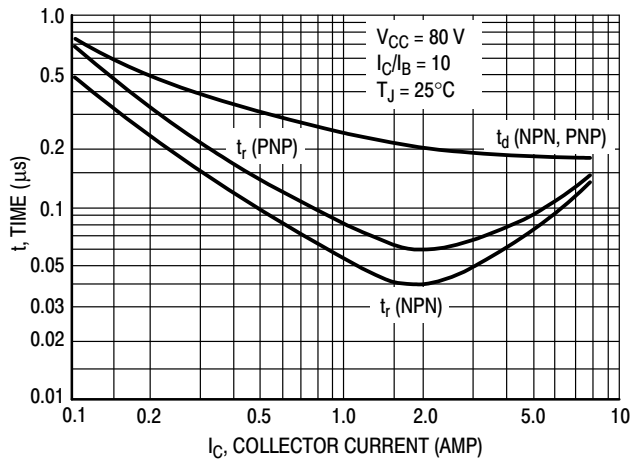


Figure 10. Turn-On Times

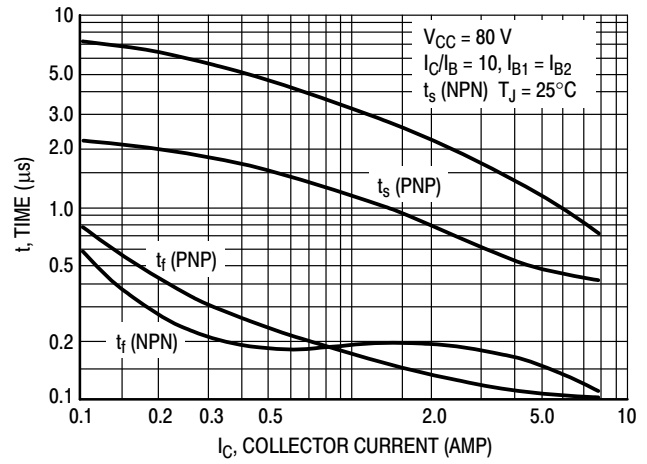


Figure 11. Turn-Off Times

### ORDERING INFORMATION

| Device    | Package             | Shipping        |
|-----------|---------------------|-----------------|
| MJE15028G | TO-220<br>(Pb-Free) | 50 Units / Rail |
| MJE15029G | TO-220<br>(Pb-Free) | 50 Units / Rail |
| MJE15030G | TO-220<br>(Pb-Free) | 50 Units / Rail |
| MJE15031G | TO-220<br>(Pb-Free) | 50 Units / Rail |

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